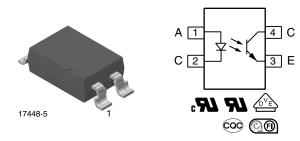


# Optocoupler, Phototransistor Output, High Reliability, 5300 V<sub>RMS</sub>



### **LINKS TO ADDITIONAL RESOURCES**



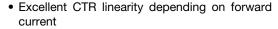


#### **DESCRIPTION**

The SFH6156 features a variety of transfer ratios, low coupling capacitance and high isolation voltage. This coupler has a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic SMD package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

#### **FEATURES**





- Isolation test voltage, 5300 V<sub>RMS</sub>
- · Fast switching times
- · Low CTR degradation
- · Low coupling capacitance
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### **APPLICATIONS**

- Switchmode power supply
- Telecom
- Battery powered equipment

#### **AGENCY APPROVALS**

The safety application model number covering all products in this datasheet is SFH615A. This model number should be used when consulting safety agency documents.

- UL 1577
- cUL
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- BSI
- CQC
- FIMKO

| ORDERING INFORMATION   |                |                |                                |                |  |  |  |
|--|----------------|----------------|--------------------------------|----------------|--|--|--|
| S F H 6 1 5 6 - # X 0 0 1 T  PART NUMBER  CTR PACKAGE OPTION TAPE AND REEL  > 8 mm |                |                |                                |                |  |  |  |
| AGENCY CERTIFIED/PACKAGE   | CTR (%)        |                |                                |                |  |  |  |
|  | 10 mA          |                |                                |                |  |  |  |
| UL, cUL, BSI, FIMKO, CQC   | 40 to 80       | 63 to 125      | 100 to 200                     | 160 to 320     |  |  |  |
| CMD 4 100 mil mitah  | SFH6156-1      | SFH6156-2      | SFH6156-3                      | SFH6156-4      |  |  |  |
| SMD-4, 100 mil, pitch  | SFH6156-1T     | SFH6156-2T     | SFH6156-3T                     | SFH6156-4T     |  |  |  |
| VDE, UL, cUL, BSI, FIMKO, CQC  | 40 to 80       | 63 to 125      | 100 to 200                     | 160 to 320     |  |  |  |
|  | SFH6156-1X001  | SFH6156-2X001  | SFH6156-3X001                  | -              |  |  |  |
| SMD-4, 100 mil, pitch  | SFH6156-1X001T | SFH6156-2X001T | SFH6156-3X001T                 | SFH6156-4X001T |  |  |  |
|  | -              | -              | SFH6156-3X001T1 <sup>(1)</sup> | -              |  |  |  |

#### Notes

- Additional options may be possible, please contact sales office
- (1) T1 rotation in tape and reel packaging



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| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                        |                  |             |    |  |  |  |  |
|--|------------------------|------------------|-------------|----|--|--|--|--|
| PARAMETER  | TEST CONDITION         | SYMBOL           | UNIT        |    |  |  |  |  |
| INPUT  |                        |                  |             |    |  |  |  |  |
| Reverse voltage  |                        | $V_R$            | 6           | V  |  |  |  |  |
| DC forward current   |                        | I <sub>F</sub>   | 60          | mA |  |  |  |  |
| Surge forward current  | t <sub>p</sub> ≤ 10 μs | I <sub>FSM</sub> | 2.5         | А  |  |  |  |  |
| OUTPUT   | ОИТРИТ                 |                  |             |    |  |  |  |  |
| Collector emitter voltage  |                        | V <sub>CEO</sub> | 70          | V  |  |  |  |  |
| Emitter collector voltage  |                        | V <sub>ECO</sub> | 7           | V  |  |  |  |  |
| Collector current  |                        | I <sub>C</sub>   | 50          | mA |  |  |  |  |
| Collector current  | t <sub>p</sub> ≤ 1 ms  | Ic               | 100         | mA |  |  |  |  |
| COUPLER  |                        |                  |             |    |  |  |  |  |
| Storage temperature range  |                        | T <sub>stg</sub> | -55 to +150 | °C |  |  |  |  |
| Ambient temperature range  |                        | T <sub>amb</sub> | -55 to +100 | °C |  |  |  |  |
| Soldering temperature (1)  | max. 10 s              | T <sub>sld</sub> | 260         | °C |  |  |  |  |

#### **Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
  implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
  maximum ratings for extended periods of the time can adversely affect reliability
- (2) Refer to reflow profile for soldering conditions for surface mounted devices (SMD)

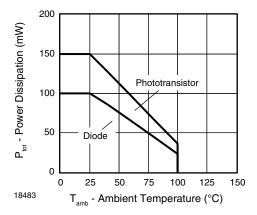


Fig. 1 - Permissible Power Dissipation vs. Ambient Temperature



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| THERMAL CHARACTERISTICS                                   |                    |       |      |
|---|--------------------|-------|------|
| PARAMETER   | SYMBOL             | VALUE | UNIT |
| LED power dissipation                                     | P <sub>diss</sub>  | 100   | mW   |
| Output power dissipation                                  | P <sub>diss</sub>  | 150   | mW   |
| Maximum LED junction temperature                          | T <sub>jmax.</sub> | 125   | °C   |
| Maximum output die junction temperature                   | T <sub>jmax.</sub> | 125   | °C   |
| Thermal resistance, junction emitter to board             | $\theta_{EB}$      | 173   | °C/W |
| Thermal resistance, junction emitter to case              | $\theta_{\sf EC}$  | 149   | °C/W |
| Thermal resistance, junction detector to board            | $\theta_{DB}$      | 111   | °C/W |
| Thermal resistance, junction detector to case             | $\theta_{DC}$      | 127   | °C/W |
| Thermal resistance, junction emitter to junction detector | $\theta_{ED}$      | 95    | °C/W |
| Thermal resistance, board to ambient (1)                  | $\theta_{BA}$      | 195   | °C/W |
| Thermal resistance, case to ambient (1)                   | $\theta_{CA}$      | 3573  | °C/W |

#### Notes

- The thermal model is represented in the thermal network below. Each resistance value given in this model can be used to calculate the
  temperatures at each node for a given operating condition. The thermal resistance from board to ambient will be dependent on the type of
  PCB, layout and thickness of copper traces. For a detailed explanation of the thermal model, please reference Vishay's thermal
  characteristics of optocouplers application note
- (1) For 2 layer FR4 board (4" x 3" x 0.062")

| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |           |                    |      |      |      |      |  |
|--|---|-----------|--------------------|------|------|------|------|--|
| PARAMETER  | TEST CONDITION                              | PART      | SYMBOL             | MIN. | TYP. | MAX. | UNIT |  |
| INPUT  | INPUT                                       |           |                    |      |      |      |      |  |
| Forward voltage  | $I_F = 60 \text{ mA}$                       |           | $V_{F}$            | -    | 1.25 | 1.65 | V    |  |
| Reverse current  | $V_R = 6 V$                                 |           | I <sub>R</sub>     | -    | 0.01 | 10   | μΑ   |  |
| Capacitance  | $V_R = 0 V$ , $f = 1 MHz$                   |           | Co                 | -    | 13   | -    | pF   |  |
| OUTPUT   | OUTPUT                                      |           |                    |      |      |      |      |  |
| Collector emitter capacitance  | $V_{CE} = 5 \text{ V}, f = 1 \text{ MHz}$   |           | C <sub>CE</sub>    | -    | 5.2  | -    | pF   |  |
|  | V <sub>CE</sub> = 10 V                      | SFH6156-1 | I <sub>CEO</sub>   | -    | 2    | 50   | nA   |  |
| Collector omitter leakage augrent  |   | SFH6156-2 | I <sub>CEO</sub>   | -    | 2    | 50   | nA   |  |
| Collector emitter leakage current  |   | SFH6156-3 | I <sub>CEO</sub>   | -    | 5    | 100  | nA   |  |
|  |   | SFH6156-4 | I <sub>CEO</sub>   | -    | 5    | 100  | nA   |  |
| COUPLER  |   |           |                    |      |      |      |      |  |
| Collector emitter saturation voltage   | $I_F = 10 \text{ mA}, I_C = 2.5 \text{ mA}$ |           | V <sub>CEsat</sub> | -    | 0.25 | 0.4  | V    |  |
| Coupling capacitance   |   |           | C <sub>C</sub>     | -    | 0.4  | -    | pF   |  |

### Note

 Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements



| CURRENT TRANSFER RATIO         |   |           |        |      |      |      |      |  |
|--------------------------------|---|-----------|--------|------|------|------|------|--|
| PARAMETER                      | TEST CONDITION                                | PART      | SYMBOL | MIN. | TYP. | MAX. | UNIT |  |
|                                | I <sub>F</sub> = 10 mA, V <sub>CE</sub> = 5 V | SFH6156-1 | CTR    | 40   | ı    | 80   | %    |  |
|                                |   | SFH6156-2 | CTR    | 63   | ı    | 125  | %    |  |
|                                |   | SFH6156-3 | CTR    | 100  | -    | 200  | %    |  |
| 1-/1-                          |   | SFH6156-4 | CTR    | 160  | -    | 320  | %    |  |
| I <sub>C</sub> /I <sub>F</sub> | I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 5 V  | SFH6156-1 | CTR    | 13   | 30   | ı    | %    |  |
|                                |   | SFH6156-2 | CTR    | 22   | 45   | -    | %    |  |
|                                |   | SFH6156-3 | CTR    | 34   | 70   | -    | %    |  |
|                                |   | SFH6156-4 | CTR    | 56   | 90   | -    | %    |  |

| <b>SWITCHING CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |           |                  |      |      |      |      |
|---|--|-----------|------------------|------|------|------|------|
| PARAMETER   | TEST CONDITION                                     | PART      | SYMBOL           | MIN. | TYP. | MAX. | UNIT |
| NON-SATURATED   |  |           |                  |      |      |      |      |
| Turn-on time  | $I_F$ = 10 mA, $V_{CC}$ = 5 V, $R_L$ = 75 $\Omega$ |           | t <sub>on</sub>  | -    | 3    | -    | μs   |
| Rise time   | $I_F$ = 10 mA, $V_{CC}$ = 5 V, $R_L$ = 75 $\Omega$ |           | t <sub>r</sub>   | -    | 2    | -    | μs   |
| Turn-off time   | $I_F$ = 10 mA, $V_{CC}$ = 5 V, $R_L$ = 75 $\Omega$ |           | t <sub>off</sub> | -    | 2.3  | -    | μs   |
| Fall time   | $I_F$ = 10 mA, $V_{CC}$ = 5 V, $R_L$ = 75 $\Omega$ |           | t <sub>f</sub>   | -    | 2    | -    | μs   |
| Cut-off frequency   | $I_F$ = 10 mA, $V_{CC}$ = 5 V, $R_L$ = 75 $\Omega$ |           | f <sub>CO</sub>  | -    | 250  | -    | kHz  |
| SATURATED   |  |           |                  |      |      |      |      |
|   | I <sub>F</sub> = 20 mA                             | SFH6156-1 | t <sub>on</sub>  | -    | 3    | -    | μs   |
| Turn-on time  | I <sub>F</sub> = 10 mA                             | SFH6156-2 | t <sub>on</sub>  | -    | 4.2  | -    | μs   |
| rum-on time   |  | SFH6156-3 | t <sub>on</sub>  | -    | 4.2  | -    | μs   |
|   | I <sub>F</sub> = 5 mA                              | SFH6156-4 | t <sub>on</sub>  | -    | 6    | -    | μs   |
|   | I <sub>F</sub> = 20 mA                             | SFH6156-1 | t <sub>r</sub>   | -    | 2    | -    | μs   |
| Diag time   | I <sub>F</sub> = 10 mA                             | SFH6156-2 | t <sub>r</sub>   | -    | 3    | -    | μs   |
| Rise time   |  | SFH6156-3 | t <sub>r</sub>   | -    | 3    | -    | μs   |
|   | I <sub>F</sub> = 5 mA                              | SFH6156-4 | t <sub>r</sub>   | -    | 4    | -    | μs   |
|   | I <sub>F</sub> = 20 mA                             | SFH6156-1 | t <sub>off</sub> | -    | 18   | -    | μs   |
| Turn-off time   | I <sub>E</sub> = 10 mA                             | SFH6156-2 | t <sub>off</sub> | -    | 23   | -    | μs   |
| rum-on time   | IF = 10 IIIA                                       | SFH6156-3 | t <sub>off</sub> | -    | 23   | -    | μs   |
|   | I <sub>F</sub> = 5 mA                              | SFH6156-4 | t <sub>off</sub> | -    | 25   | -    | μs   |
|   | I <sub>F</sub> = 20 mA                             | SFH6156-1 | t <sub>f</sub>   | -    | 11   | -    | μs   |
| Fall time   | L = 10 mA  | SFH6156-2 | t <sub>f</sub>   | -    | 14   | -    | μs   |
| Fall time   | $I_F = 10 \text{ mA}$                              | SFH6156-3 | t <sub>f</sub>   | -    | 14   | -    | μs   |
|   | I <sub>F</sub> = 5 mA                              | SFH6156-4 | t <sub>f</sub>   | -    | 15   | -    | μs   |



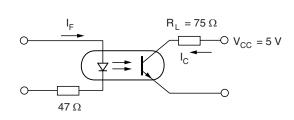
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| SAFETY AND INSULATION RATINGS                |   |                   |                    |                  |  |  |  |
|--|---|-------------------|--------------------|------------------|--|--|--|
| PARAMETER                                    | TEST CONDITION  | SYMBOL            | VALUE              | UNIT             |  |  |  |
| Climatic classification                      | According to IEC 68 part 1                              |                   | 55/100/21          |                  |  |  |  |
| Comparative tracking index                   |   | CTI               | 175                |                  |  |  |  |
| Maximum rated withstanding isolation voltage | t = 1 min   | V <sub>ISO</sub>  | 4420               | V <sub>RMS</sub> |  |  |  |
| Maximum transient isolation voltage          |   | V <sub>IOTM</sub> | 10 000             | V                |  |  |  |
| Maximum repetitive peak isolation voltage    |   | V <sub>IORM</sub> | 890                | V                |  |  |  |
| Isolation resistance                         | $V_{IO} = 500 \text{ V}, T_{amb} = 25 ^{\circ}\text{C}$ | R <sub>IO</sub>   | ≥ 10 <sup>12</sup> | Ω                |  |  |  |
| Isolation resistance                         | V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C      | R <sub>IO</sub>   | ≥ 10 <sup>11</sup> | Ω                |  |  |  |
| Output safety power                          |   | P <sub>SO</sub>   | 400                | mW               |  |  |  |
| Input safety current                         |   | I <sub>SI</sub>   | 275                | mA               |  |  |  |
| Input safety temperature                     |   | T <sub>SI</sub>   | 175                | °C               |  |  |  |
| Creepage distance                            |   |                   | ≥ 7                | mm               |  |  |  |
| Clearance distance                           |   |                   | ≥ 7                | mm               |  |  |  |
| Insulation thickness                         |   | DTI               | ≥ 0.4              | mm               |  |  |  |

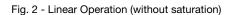
#### Note

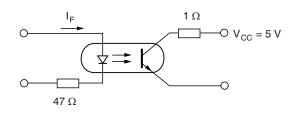
## TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)



isfh615a\_01

Fig. 4 - Current Transfer Ratio (typ.) vs. Temperature





isfh615a\_02

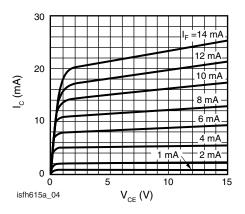


Fig. 3 - Switching Operation (with saturation)

Fig. 5 - Output Characteristics (typ.) Collector Current vs. Collector Emitter Voltage

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits



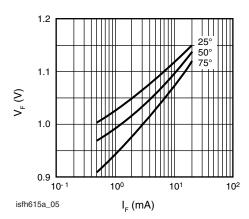


Fig. 6 - Diode Forward Voltage (typ.) vs. Forward Current

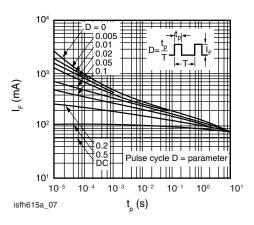


Fig. 8 - Permissible Pulse Handling Capability Forward Current vs. Pulse Width

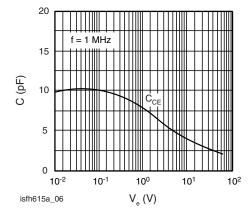
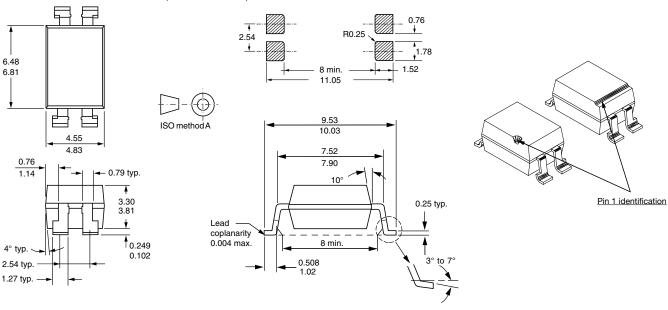


Fig. 7 - Transistor Capacitance (typ.) vs. Collector Emitter Voltage

## **PACKAGE DIMENSIONS** (in millimeters)



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## PACKAGE MARKING (example of SFH6156-2X001T)



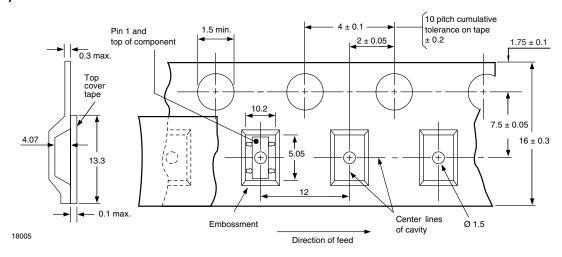
#### Notes

- · VDE logo is only marked on option 1 parts
- Tape and reel suffix (T) is not part of the package marking

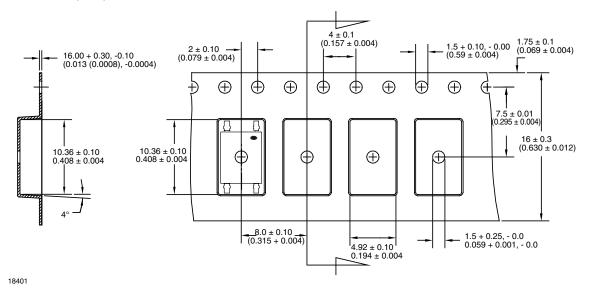
### TAPE AND REEL PACKAGING (in millimeters)

The tape is 16 mm and is wound on a 33 cm reel. There are 1000 parts per reel. Taped and reeled 4 pin optocouplers conform to EIA-481-2 and IEC60286-3.

#### SMD-4 ("T")



#### SMD-4, 90° Rotation ("T1")





### **SOLDER PROFILES**

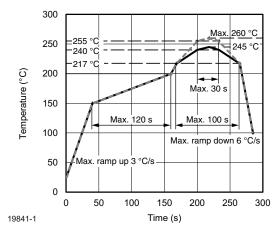


Fig. 9 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD Devices

### HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions:  $T_{amb}$  < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020

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